Power MOSFET 2.0 A, 60 V, Logic Level

N-Channel SOT-223

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

Features

• This is a Pb–Free Device

Applications

- Power Supplies
- Converters
- Power Motor Controls
- Bridge Circuits

MAXIMUM RATINGS (T_C = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit			
Drain-to-Source Voltage	V _{DSS}	60	Vdc			
Drain-to-Gate Voltage (R_{GS} = 1.0 M Ω)	V _{DGR}	60	Vdc			
Gate–to–Source Voltage Continuous Non–repetitive (t _p ≤ 10 ms)	V _{GS}	± 15 ± 20	Vdc Vpk			
Drain Current Continuous @ $T_A = 25^{\circ}C$ Continuous @ $T_A = 100^{\circ}C$ Single Pulse ($t_p \le 10 \ \mu s$)	I _D ID IDM	2.0 1.2 6.0	Adc Apk			
Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 1) Total Power Dissipation @ $T_A = 25^{\circ}C$ (Note 2) Derate above $25^{\circ}C$	P _D	2.1 1.3 0.014	W ₩ ₩/°C			
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to 175	°C			
$ Single Pulse Drain-to-Source Avalanche \\ Energy - Starting T_J = 25^\circ C \\ (V_{DD} = 25 \text{ Vdc}, \text{ V}_{GS} = 5.0 \text{ Vdc}, \\ I_{L(pk)} = 3.6 \text{ A}, L = 10 \text{ mH}, \text{ V}_{DS} = 60 \text{ Vdc}) $	E _{AS}	65	mJ			
Thermal Resistance Junction-to-Ambient (Note 1) Junction-to-Ambient (Note 2)	${f R}_{ heta JA} {f R}_{ heta JA}$	72.3 114	°C/W			
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	ΤL	260	°C			

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

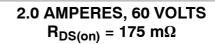
 When surface mounted to an FR4 board using 1" pad size, 1 oz. (Cu. Area 0.995 in²).

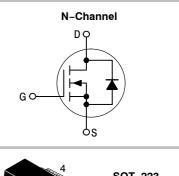
 When surface mounted to an FR4 board using minimum recommended pad size, 2–2.4 oz. (Cu. Area 0.272 in²).



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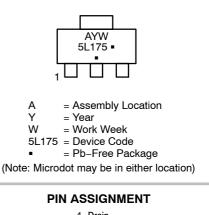
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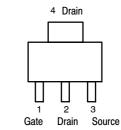






MARKING DIAGRAM





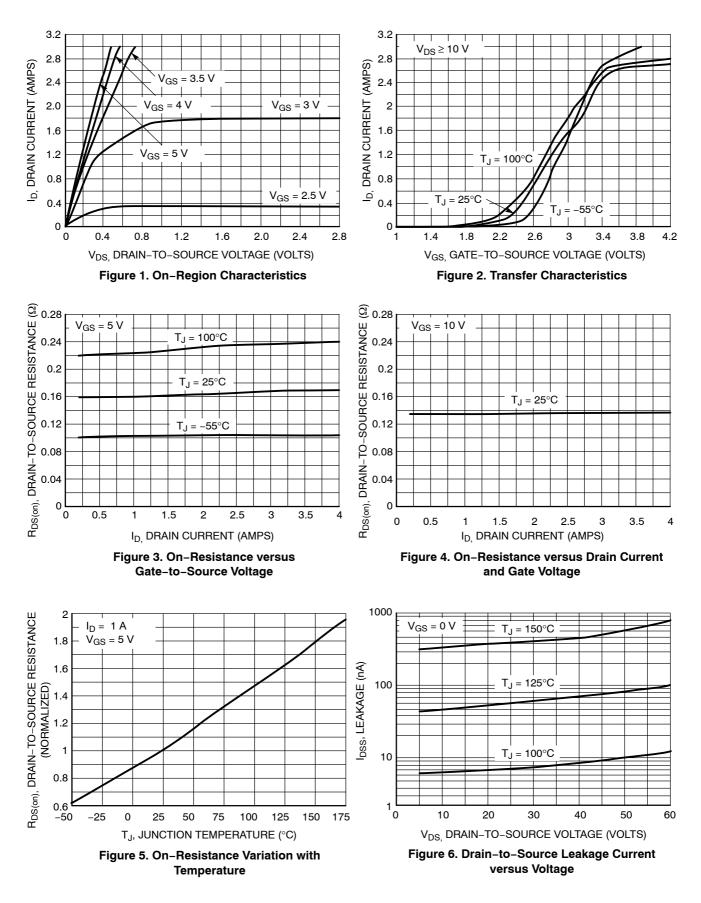
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

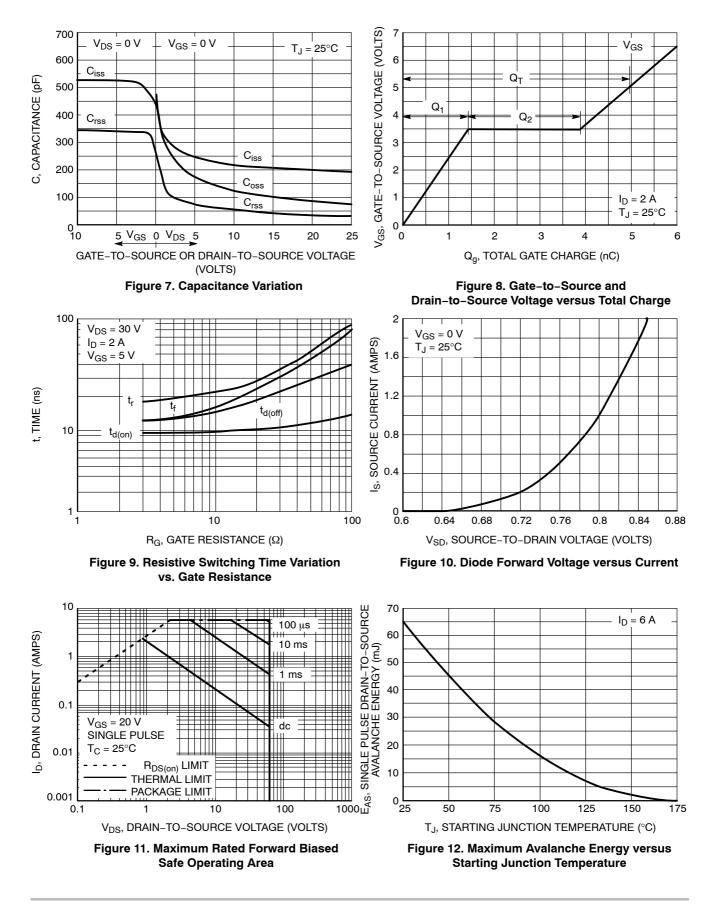
ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Char	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS			•	•	-	
Drain-to-Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 250 μAdc) Temperature Coefficient (Positive)	V _{(BR)DSS}	60 -	72.8 74.4		Vdc mV/°C	
Zero Gate Voltage Drain Current ($V_{DS} = 60$ Vdc, $V_{GS} = 0$ Vdc) ($V_{DS} = 60$ Vdc, $V_{GS} = 0$ Vdc, $T_J = 0$	I _{DSS}			1.0 10	μAdc	
Gate-Body Leakage Current (V _{GS} =	I _{GSS}	-	-	± 100	nAdc	
ON CHARACTERISTICS (Note 3)						
Gate Threshold Voltage (Note 3) $(V_{DS} = V_{GS}, I_D = 250 \ \mu Adc)$ Threshold Temperature Coefficien	V _{GS(th)}	1.0 -	1.7 4.2	2.0 _	Vdc mV/°C	
Static Drain-to-Source On-Resistant (V_{GS} = 5.0 Vdc, I_D = 1.0 Adc)	R _{DS(on)}	-	155	175	mΩ	
$ Static Drain-to-Source On-Resistant \\ (V_{GS} = 5.0 \text{ Vdc}, \text{ I}_{D} = 2.0 \text{ Adc}) \\ (V_{GS} = 5.0 \text{ Vdc}, \text{ I}_{D} = 1.0 \text{ Adc}, \text{ T}_{J} = 1.0 \text{ Adc}, \\ 1 = 1.0 \text{ Adc}, \text{ T}_{J} = 1.0 \text{ Adc}, \\ 1 = 1.0 \text{ Adc}, \text{ T}_{J} = 1.0 \text{ Adc}, \\ 1 = 1.0 \text{ Adc}, \\ 1$	V _{DS(on)}	-	0.32 0.57	0.42 -	Vdc	
Forward Transconductance (Note 3) $(V_{DS} = 8.0 \text{ Vdc}, I_D = 1.5 \text{ Adc})$	9 _{fs}	-	3.2	-	Mhos	
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	194	270	pF
Output Capacitance	(V_{DS} = 25 Vdc, V_{GS} = 0 V, f = 1.0 MHz)	Coss	-	70	100	
Transfer Capacitance		C _{rss}	-	29	40	
SWITCHING CHARACTERISTICS (N	ote 4)					
Turn-On Delay Time		t _{d(on)}	-	10.2	20	ns
Rise Time	(V _{DD} = 30 Vdc, I _D = 2.0 Adc,	t _r	-	21	40	
Turn-Off Delay Time	$V_{GS} = 5.0 \text{ Vdc}, R_G = 9.1 \Omega$ (Note 3)	t _{d(off)}	-	14.3	30	
Fall Time		t _f	-	15.3	30	
Gate Charge		QT	-	5.1	10	nC
	(V _{DS} = 48 Vdc, I _D = 2.0 Adc, V _{GS} = 5.0 Vdc) (Note 3)	Q ₁	-	1.4	-	
		Q ₂	-	2.5	-	
SOURCE-DRAIN DIODE CHARACTI	ERISTICS					
Forward On-Voltage		V _{SD}		0.84 0.68	1.0 -	Vdc
Reverse Recovery Time		t _{rr}	-	28.3	-	ns
	(I _S = 2.0 Adc, V _{GS} = 0 Vdc,	t _a	-	15.6	-	1
	$dI_{S}/dt = 100 \text{ A/}\mu\text{s}$ (Note 3)	t _b	-	12.7	-	1
Reverse Recovery Stored Charge	Q _{RR}	-	0.027	-	μC	

TYPICAL ELECTRICAL CHARACTERISTICS



TYPICAL ELECTRICAL CHARACTERISTICS



TYPICAL ELECTRICAL CHARACTERISTICS

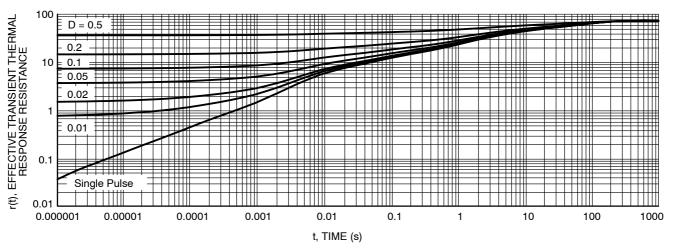


Figure 13. Thermal Response

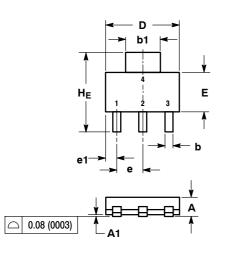
ORDERING INFORMATION

Device	Package	Shipping [†]
NTF3055L175T1G	SOT-223 (TO-261) (Pb-Free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 ISSUE N

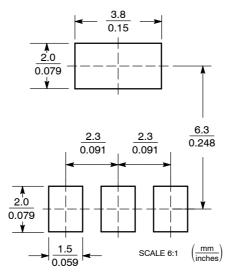


NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
c	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
Г	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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